

**SCHOTTKY BARRIER RECTIFIERS**

REVERSE VOLTAGE - 70 to 100 Volts  
FORWARD CURRENT - 16 Amperes

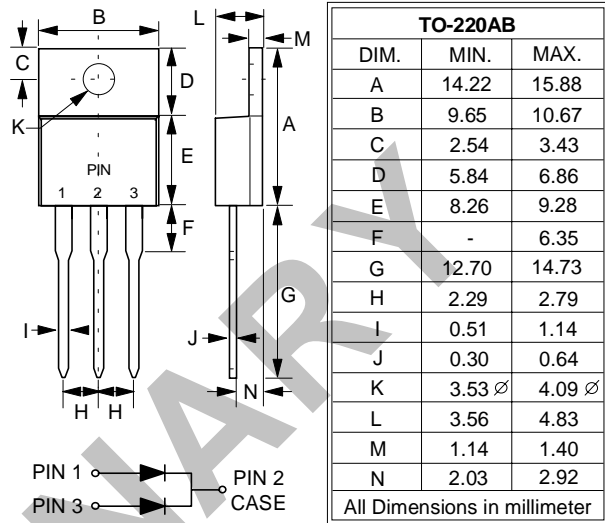
**FEATURES**

- Metal of silicon rectifier, majority carrier conduction
- Guard ring for transient protection
- Low power loss, high efficiency
- High current capability, low VF
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage, high frequency inverters, free whelling, and polarity protection applications

**MECHANICAL DATA**

- Case : TO-220AB molded plastic
- Polarity : As marked on the body
- Weight : 0.08 ounces, 2.24 grams
- Mounting position : Any

**TO-220AB**



**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Ratings at 25°C ambient temperature unless otherwise specified.  
Single phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	MBR1670CT	MBR1680CT	MBR1690CT	MBR16100CT	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	70	80	90	100	V
Maximum RMS Voltage	VRMS	49	56	63	70	V
Maximum DC Blocking Voltage	VDC	70	80	90	100	V
Maximum Average Forward Rectified Current at TC=100°C (See Fig.1)	I(AV)	16				A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC METHOD)	IFSM	125				A
Voltage Rate of Change (Rated VR)	dv/dt	10000				V/us
Maximum Forward Voltage, (Note 1)	VF	@IF=8A TJ=25°C 0.85 @IF=8A TJ=125°C 0.75 @IF=16A TJ=25°C 0.95 @IF=16A TJ=125°C 0.85				V
Maximum DC Reverse Current at Rated DC Blocking Voltage	IR	@TJ=25°C 0.1 @TJ=125°C 100				mA
Typical Junction Capacitance, per element (Note 2)	CJ	275				pF
Typical Thermal Resistance (Note 3)	RθJC	2.0				°C/W
Operating Temperature Range	TJ	-55 to +150				°C
Storage Temperature Range	TSTG	-55 to +175				°C

NOTES : 1. 300us Pulse Width, 2% Duty Cycle.  
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.  
3. Thermal Resistance Junction to Case.

